

IPP65R110CFDAAKSA1

IPP65R110CFDAAKSA1 Information



Part Number	IPP65R110CFDAAKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single
Description	MOSFET N-CH 650V TO-220-3
Package	TO-220-3
	For the pricing/inventory/lead time, please contact
	us
	Website: https://www.heisener.com
	E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPP65R110CFDAAKSA1 Specifications

Manufacturer Part Number	IPP65R110CFDAAKSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-220-3
Series	Automotive, AEC-Q101, CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	650V
Current - Continuous Drain (Id) @ 25°C	31.2A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 1.3mA
Gate Charge (Qg) (Max) @ Vgs	118nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3240pF @ 100V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	277.8W (Tc)
Rds On (Max) @ Id, Vgs	110 mOhm @ 12.7A, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	PG-TO-220-3
Package / Case	TO-220-3
	Report errors?

IPP65R110CFDAAKSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IPP65R110CFDAAKSA1 Payment Methods



If you have any question about IPP65R110CFDAAKSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com